



M74HC4316

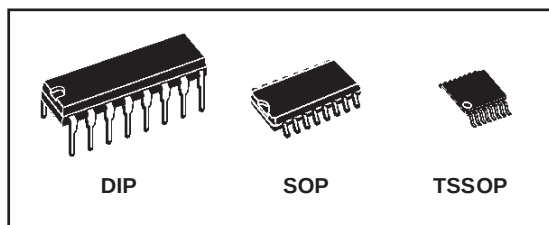
QUAD BILATERAL SWITCH

- HIGH SPEED:
 $t_{PD} = 13\text{ns}$ (TYP.) at $V_{CC} = 6\text{V}$
- LOW POWER DISSIPATION:
 $I_{CC} = 1\mu\text{A}$ (MAX.) at $V_{CC} = 5\text{V}$
- LOW "ON" RESISTANCE:
120 Ω TYP. ($V_{CC} - V_{EE} = 2\text{V}$)
50 Ω TYP. ($V_{CC} - V_{EE} = 4.5\text{V}$)
35 Ω TYP. ($V_{CC} - V_{EE} = 9\text{V}$)
- WIDE ANALOG INPUT VOLTAGE RANGE $\pm 6\text{V}$
- LOW CROSSTALK BETWEEN SWITCHES
- FAST SWITCHING
- SINE WAVE DISTORTION:
0.020 at $V_{CC} - V_{EE} = 9\text{V}$
- HIGH NOISE IMMUNITY:
 $V_{NIH} = V_{NIL} = 28\%$ V_{CC} (MIN.)
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 4316

DESCRIPTION

The M74HC4316 is an high speed CMOS QUAD BILATERAL SWITCH fabricated with silicon gate C²MOS technology.

This device has four independent analogue switches. Each switch has two input/output terminals (n/I, n/O) and an active high select input (nC).



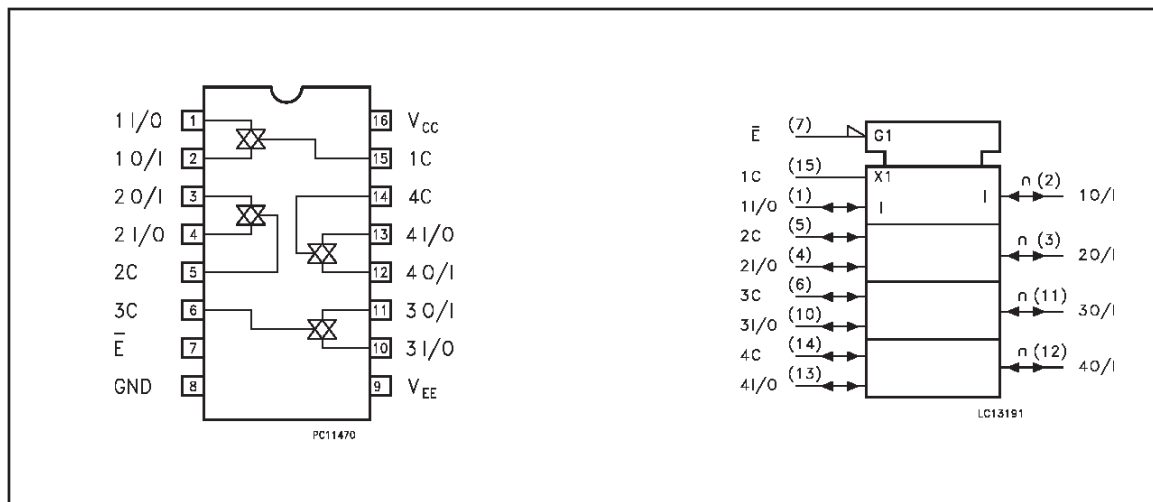
ORDER CODES

PACKAGE	TUBE	T & R
DIP	M74HC4316B1R	
SOP	M74HC4316M1R	M74HC4316RM13TR
TSSOP		M74HC4316TTR

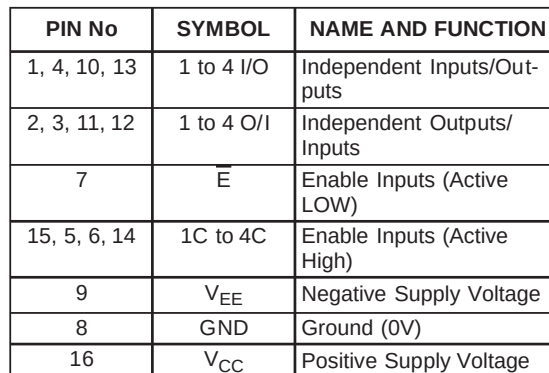
When the enable input is high, all four analog switches are off. The supply voltage for the digital signals applied to V_{CC} and GND must be within the range 0 to 6 V. The voltage swing on the analogue Inputs/Outputs can be between V_{CC} (positive limit) and V_{EE} (negative limit). The voltage between V_{CC} and V_{EE} must not exceed 12V.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

PIN CONNECTION AND IEC LOGIC SYMBOLS



PIN DESCRIPTION



$\bar{E}$	C	SWITCH FUNCTION
L	H	ON
L	L	OFF
H	X	OFF

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	-0.5 to +7	V
V _{CC} - V _{EE}	Supply Voltage	-0.5 to +13	V
V _I	Control Input Voltage	-0.5 to V _{CC} + 0.5	V
V _{I/O}	Switch Input/Output Voltage	V _{EE} -0.5 to V _{CC} + 0.5	V
I _{IK}	DC Input Diode Current	± 20	mA
I _{OK}	DC Output Diode Current	± 20	mA
I _O	DC Output Source Sink Current Per Output Pin	± 25	mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current	± 50	mA
P _D	Power Dissipation	500(*)	mW
T _{stg}	Storage Temperature	-65 to +150	°C
T _L	Lead Temperature (10 sec)	300	°C

(*) 500mW at 65 °C; derate to 300mW by 10mW/°C from 65°C to 85°C

M74HC4316**RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	2 to 12	V
V_{EE}	Supply Voltage	-6 to 0	V
$V_{CC} - V_{EE}$	Supply Voltage	2 to 12	V
V_I	Input Voltage	0 to V_{CC}	V
$V_{I/O}$	Switch I/O Voltage	0 to V_{CC}	V
T_{op}	Operating Temperature	-55 to 125	°C
t_r, t_f	Input Rise and Fall Time	$V_{CC} = 2.0V$	0 to 1000
		$V_{CC} = 4.5V$	0 to 500
		$V_{CC} = 6.0V$	0 to 400

DC SPECIFICATIONS

Symbol	Parameter	Test Condition			Value						Unit		
		V _{CC} (V)	V _{EE} (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C			
					Min.	Typ.	Max.	Min.	Max.	Min.		Max.	
V _{IHC}	High Level Control Input Voltage	2.0			1.5			1.5		1.5		V	
		4.5			3.15			3.15		3.15			
		6.0			4.2			4.2		4.2			
V _{ILC}	Low Level Control Input Voltage	2.0					0.5		0.5		0.5	V	
		4.5					1.35		1.35		1.35		
		6.0					1.8		1.8		1.8		
R _{ON}	ON Resistance	4.5	GND	V _I = V _{IHC} V _{I/O} = V _{CC} to V _{EE} I _{I/O} = 0.1mA		70	170		200			Ω	
		4.5	-4.5			50	85		105				
		6.0	-6.0			30	70		85				
		2.0	GND	V _I = V _{IHC} V _{I/O} = V _{CC} or V _{EE} I _{I/O} = 0.1mA		120	180		215				
		4.5	GND			50	80		100				
		4.5	-4.5			35	60		75				
		6.0	-6.0			20	40		60				
ΔR _{ON}	Difference of ON Resistance between switches	4.5	GND	V _{IN} = V _{IHC} or V _{ILC}		10	15		20			Ω	
		4.5	-4.5	V _{I/O} = V _{CC} to V _{EE}		5	10		15				
		6.0	-6.0	I _{I/O} = 0.1mA		5	10		15				
I _{OFF}	Input/Output Leakage Current (SWITCH OFF)	6.0	GND	V _{OS} = V _{CC} or GND			±0.06		± 0.6		± 2	μA	
		6.0	-6.0	V _{IS} = V _{CC} or GND V _{IN} = V _{IHC} or V _{ILC}			± 0.1		± 1		± 2		
I _{IZ}	Switch Input Leakage Current (SWITCH ON, OUTPUT OPEN)	6.0	GND	V _{OS} = V _{CC} or GND			±0.06		± 0.6		± 2	μA	
		6.0	-6.0	V _{IN} = V _{IHC} or V _{ILC}			± 0.1		± 1		± 2		
I _{IN}	Control Input Current	6.0		V _I = V _{CC} or GND		10 ⁻⁵	± 0.1		± 1		± 1	μA	

M74HC4316**AC ELECTRICAL CHARACTERISTICS** ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

Symbol	Parameter	Test Condition			Value						Unit	
		V _{CC} (V)	V _{EE} (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		
					Min.	Typ.	Max.	Min.	Max.	Min.		Max.
Φ _{I/O}	Phase Difference Between Input and Output	2.0	GND			12	30		40			ns
		4.5	GND			3	6		8			
		6.0	GND			3	5		7			
		4.5	-4.5			2	4		5			
		6.0	-6.0			2	4		5			
t _{PZL} t _{PZH}	Output Enable Time (E, C - OUT)	2.0	GND	R _L = 1KΩ		56	115		145			ns
		4.5	GND			14	23		29			
		6.0	GND			12	20		25			
		4.5	-4.5			13	21		26			
		6.0	-6.0			11	18		23			
t _{PLZ} t _{PHZ}	Output Disable Time (E, C - OUT)	2.0	GND	R _L = 1KΩ		112	205		255			ns
		4.5	GND			28	41		51			
		6.0	GND			24	35		43			
		4.5	-4.5			24	34		43			
		6.0	-6.0			21	29		36			
f _{MAX}	Maximum Control Input Frequency	2.0	GND	R _L = 1KΩ C _L = 15 pF V _{OUT} = 1/2 V _{CC}		2						MHz
		4.5	GND			9						
		6.0	GND			11						

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Condition		Value						Unit	
		V _{CC} (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
C _{IN}	Input Capacitance				5	10		10		10	pF
C _{I/O}	Switch Terminal Capacitance	4.5	-4.5		5						pF
C _{IOS}	Feed Through Capacitance	4.5	-4.5		1						pF
C _{PD}	Power Dissipation Capacitance (note 1)	5.0	GND		16						pF

1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$

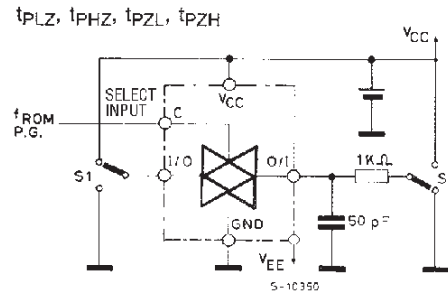
M74HC4316**ANALOG SWITCH CHARACTERISTICS (GND = 0V; T_A = 25°C)**

Symbol	Parameter	Test Condition			Value	Unit
		V _{CC} (V)	V _{EE} (V)	V _{IN} (V _{p-p})	Typ.	
	Sine Wave Distortion (THD)	2.25	2.25	4	0.025	%
		4.5	4.5	8	0.020	
		6.0	6.0	11	0.018	
f _{MAX}	Frequency Response (Switch ON)	2.25	2.25	Adjust f _{IN} voltage to obtain 0 dBm at V _{OS} . Increase f _{IN} Frequency until dB meter reads -3dB R _L = 50Ω, C _L = 10 pF, f _{IN} = 1MHz sine wave	28	MHz
		4.5	4.5		42	
		6.0	6.0		43	
	Feed through Attenuation (Switch OFF)	2.25	2.25	V _{IN} is centered at V _{CC} /2. Adjust input for 0 dBm R _L = 600Ω, C _L = 50 pF, f _{IN} = 1MHz sine wave	-50	dB
		4.5	4.5		-50	
		6.0	6.0		-50	
	Crosstalk (Control Input to Signal Output)	2.25	2.25	R _L = 600Ω, C _L = 50 pF, f _{IN} = 1MHz square wave (t _r = t _f = 6ns)		mV
		4.5	4.5		5	
		6.0	6.0			
	Crosstalk (Between Any Switches)	2.25	2.25	Adjust V _{IN} to Obtain 0 dBm at input R _L = 600Ω, C _L = 50 pF, f _{IN} = 1MHz sine wave	-50	dB
		4.5	4.5		-50	
		6.0	6.0		-50	

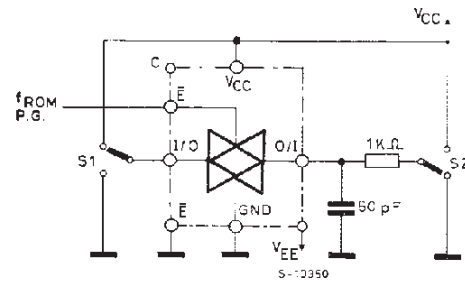
M74HC4316

SWITCHING CHARACTERISTICS TEST CIRCUIT

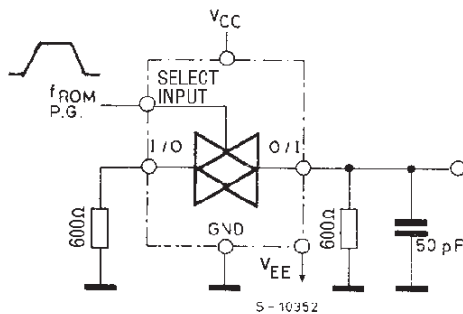
CONTROL



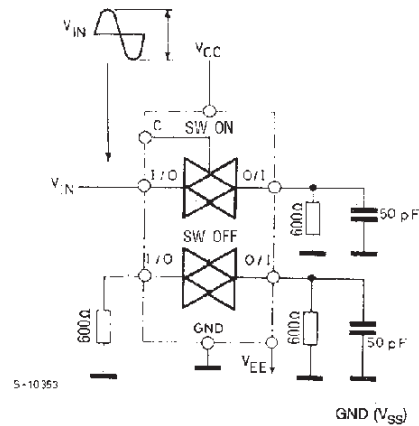
ENABLE



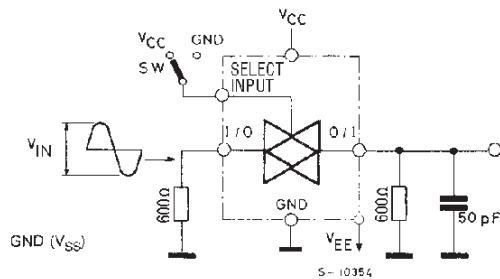
CROSSTALK (control to output)



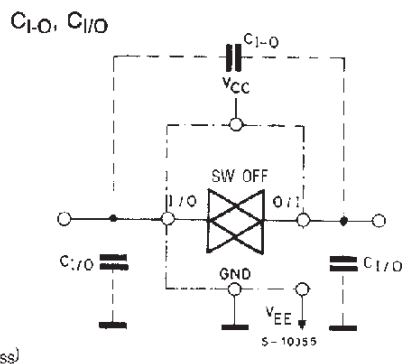
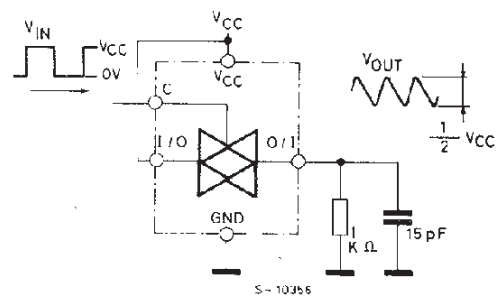
CROSSTALK BETWEEN ANY TWO SWITCHES



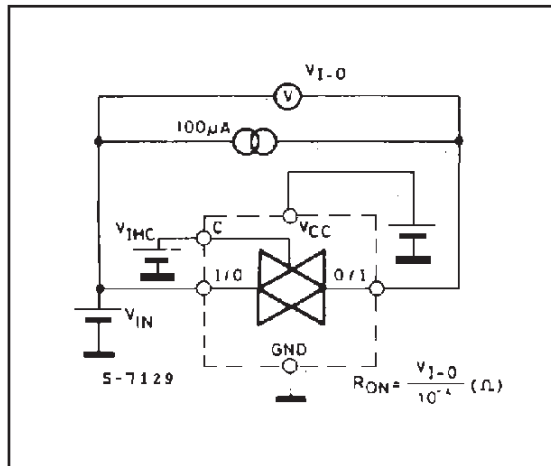
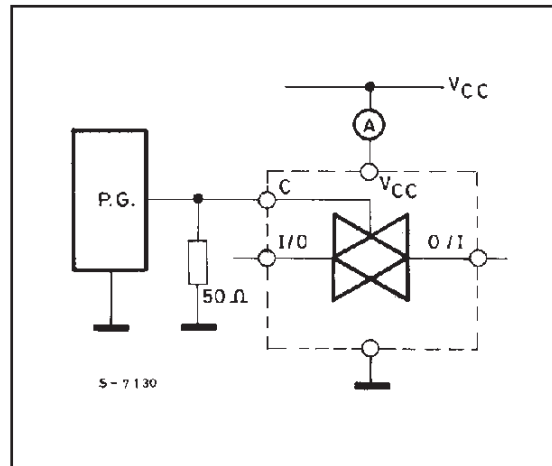
BANDWIDTH AND FEEDTHROUGH ATTENUATION



MAXIMUM CONTROL FREQUENCY

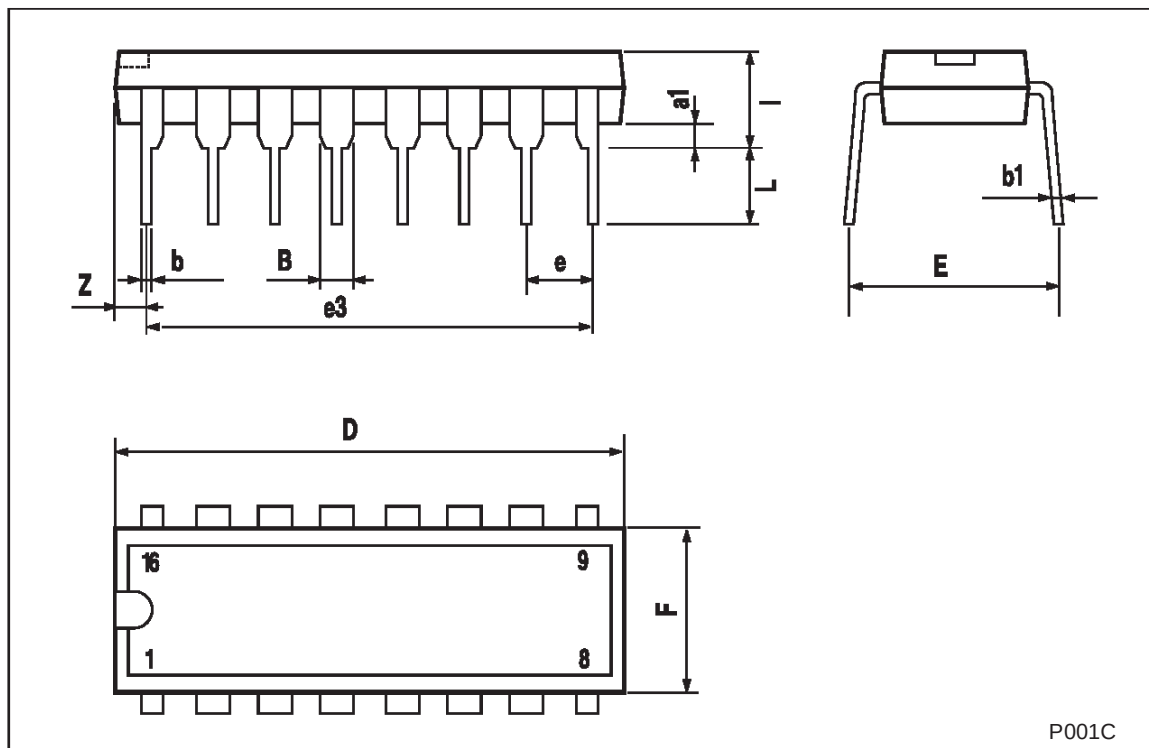


M74HC4316

CHANNEL RESISTANCE (R_{ON}) I_{CC} (Opr.)

M74HC4316**Plastic DIP-16 (0.25) MECHANICAL DATA**

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050

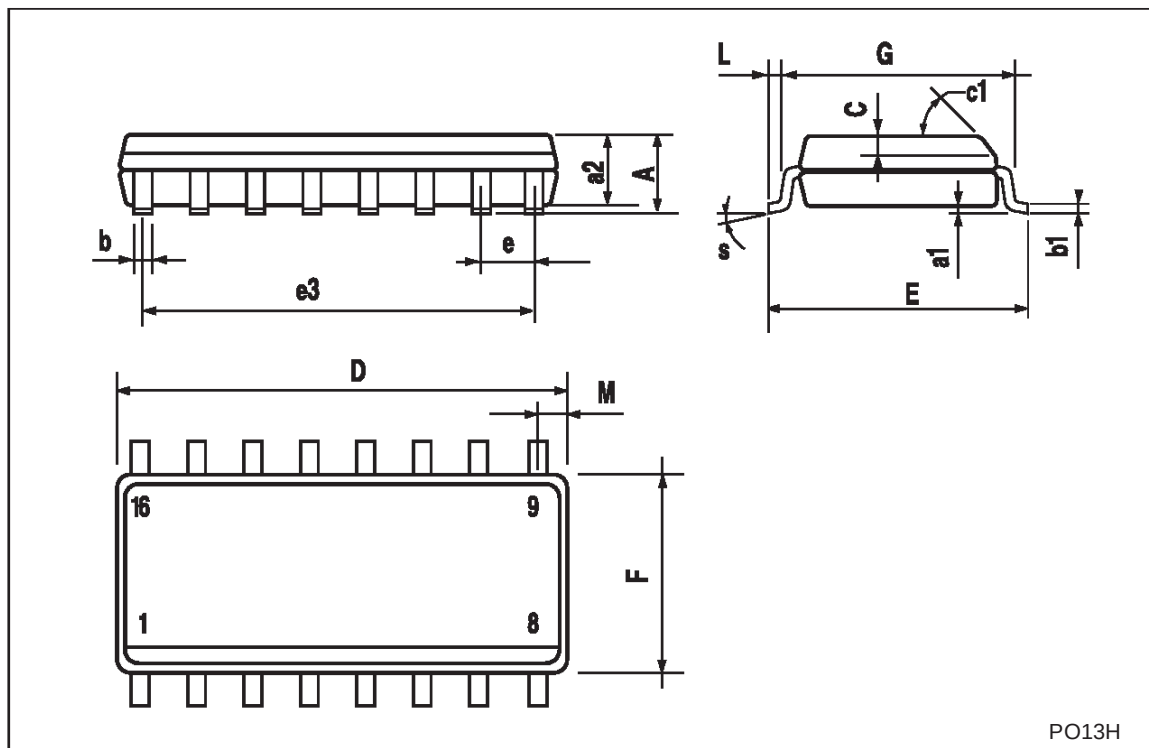


P001C

M74HC4316

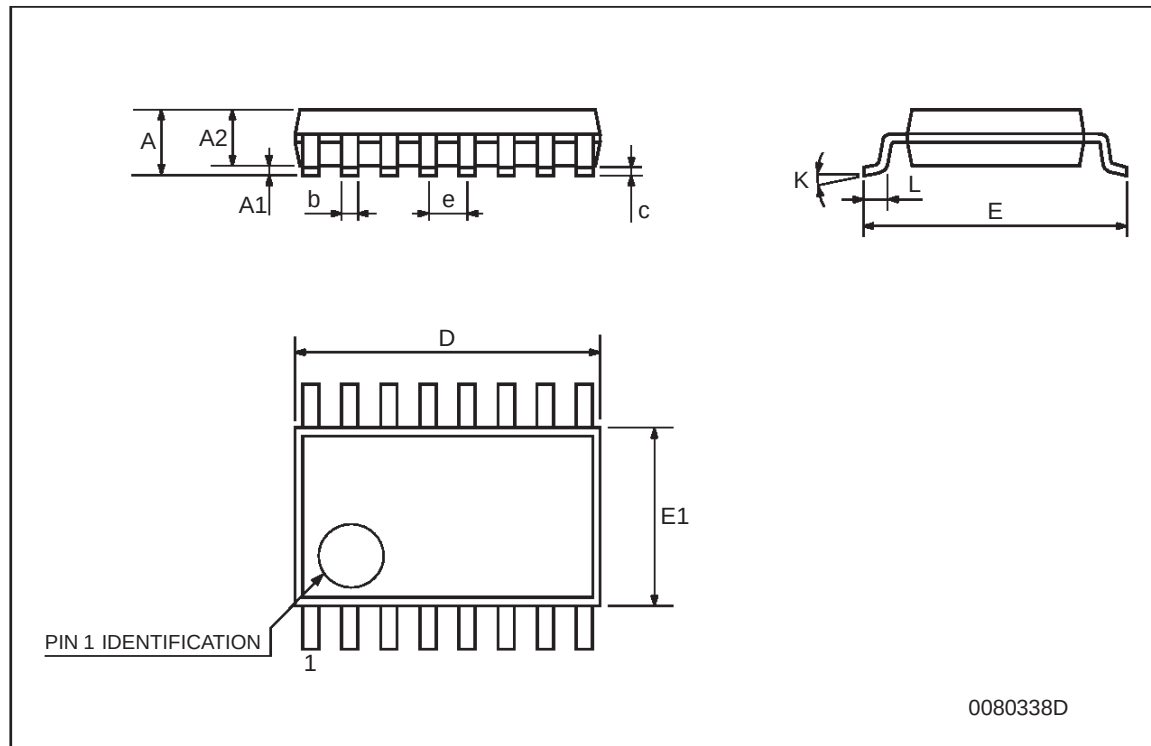
SO-16 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8° (max.)					



M74HC4316**TSSOP16 MECHANICAL DATA**

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



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